

# 600mA Low Dropout Linear Regulator

# General Description

The uP0111 is a compact fast response low dropout regulator specifically designed to continuously deliver up to 600mA output current. Designed with a P-channel MOSFET series pass transistor, the uP0111 yields extremely low dropout voltage (e.g. 300mV at 600mA) and maintains very low quiescent current (70uA).

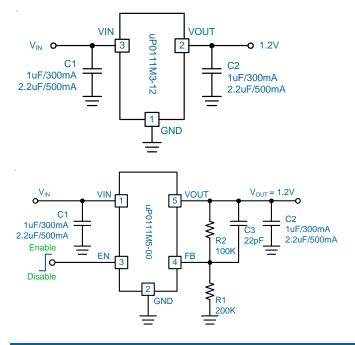
The uP0111 does not require a bypass capacitor, hence achieving the smallest PCB area. The uP0111 is designed and optimized to work with low-value, low-cost ceramic capacitors. Only a 1uF ceramic output capacitor is required for stable operation for any load conditions.

Other features include foldback overcurrent protection, quick soft start, and over temperature protection. The uP0111 is available in fixed output voltage from 0.8V to 3.3V with 0.1V per step or as an adjustable device with a 0.8V reference voltage. The device comes in various packages.

# **Applications**

- Cellular and Cordless Phones
- Bluetooth Portable Radios and Accessaries
- Battery-Powered Equipment
- Laptop, Palmtops, Notebook Computers
- Hand-Held Instruments
- PCMCIA Cards
- Portable Information Appliances

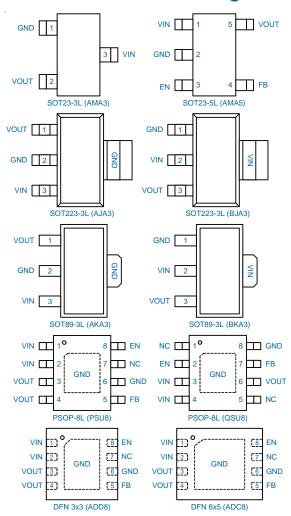
# **Typical Application Circuit**



# . Features

- Wide Input Voltage Range from 2.5V to 5.5V
- Ultra Low Dropout Voltage: 300mV @ 600mA
- Ultra Fast Response in Line/Load Transient
- Stable with 1uF Ceramic Output Capacitor
- Low Quiescent Current: 70uA Typical
- Low Shutdown Current: < 1uA</p>
- Foldback Output Current Limit
- High Output Accuracy
  - 1.5% Initial Accuracy
  - Fixed Output Voltages: 0.8V to 3.3V
  - Adjustable Output Voltage from 0.8V to 4.5V
- Over-Temperature Protection
- RoHS Compliant and Halogen Free

# **Pin Configuration**



Note: The figures are not to scale



# Ordering Information

Order Number	Package	Top Marking	Remark
uP0111AMA3-XX	SOT23-3L	S51AXX	
uP0111AMA5-XX	SOT23-5L	S43AXX	
uP0111AJA3-XX	SOT223-3L	TBD	XX: Voltage Options
uP0111BJA3-XX	SOT223-3L	TBD	00: Adjustable Output Voltage
uP0111AKA3-XX	SOT89-3L	109-3L   10D   '	10: 1.0V; 12: 1.2V 15: 1.5V; 18: 1.8V; 25: 2.5V; 28: 2.8V; 30: 3.0V; 33: 3.3V
uP0111BKA3-XX	SOT89-3L	TBD	(00 version is not available for 3-lead
uP0111PDD8-XX	DFN3x3-8L	D8PXX	packages )
uP0111PDC8-XX	DFN6x5-8L	TBD	
uP0111PSU8-XX	PSOP-8L	uP0111PXX	
uP0111QSU8-XX	PSOP-8L	TBD	

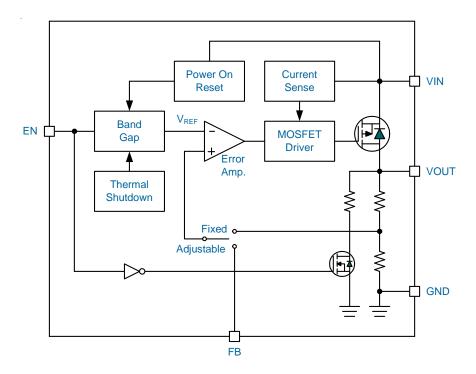
Note: uPI products are compatible with the current IPC/JEDEC J-STD-020 requirement. They are halogen-free, RoHS compliant and 100% matte tin (Sn) plating that are suitable for use in SnPb or Pb-free soldering processes.

# Functional Pin Description

Pin No.	Pin Name	Pin Function
1	VIN	<b>Input Voltage.</b> This pin connects to the source of the internal pass transistor that supplies current to the output pin. Bypass VIN to GND with a minimum 1uF ceramic capacitor. Place the decoupling capacitor physically as close as possible to the device.
2	GND	Ground.
3	EN	<b>Enable Input.</b> Pulling this pin below 0.35V turns the regulator off, reducing the quiescent current to a fraction of its operating value. This pin is not available for 3-pin packages.
4	FB	<b>Feedback Pin (Adjustable Version).</b> This pin is the non-inverting input of the error amplifier. The FB pin voltage is regulated to $0.8V$ reference voltage. Set the output voltage according to $V_{OUT} = 0.8 \times (R1 + R2)/R1$ (V). This pin is not internally connected for the fixed output version.
5	VOUT	<b>Output Voltage.</b> This pin is power output of the device. A pull low resistance exists when the device is disabled by pulling low the EN pin. To maintain adequate transient response to large load change, a minimum 1uF ceramic capacitor is required to reduce the effects of current transients on VOUT.



# Functional Block Diagram



# **Functional Description**

### **Definitions**

Some important terminologies for LDO are specified below.

### **Dropout Voltage**

The input/output Voltage differential at which the regulator output no longer maintains regulation against further reductions in input voltage. Measured when the output drops 2% below its nominal value, dropout voltage is affected by junction temperature, load current and minimum input supply requirements.

### **Line Regulation**

The change in output voltage for a change in input voltage. The measurement is made under conditions of low dissipation or by using pulse techniques such that average chip temperature is not significantly affected.

### **Load Regulation**

The change in output voltage for a change in load current at constant chip temperature. The measurement is made under conditions of low dissipation or by using pulse techniques such that average chip temperature is not significantly affected.

Maximum Power Dissipation The maximum total device dissipation for which the regulator will operate within specifications.

### **Quiescent Bias Current**

Current which is used to operate the regulator chip and is not delivered to the load. The quiescent current  $I_Q$  is defined as the supply current used by the regulator itself that does not pass into the load. It typically includes all bias currents required by the LDO and any drive current for the pass transistor.

The uP0111 is a compact fast transient response low dropout regulator specifically designed to continuously deliver up to 600mA output current for space-limited applications. Designed with a P-channel MOSFET series pass transistor, the uP0111 yields extremely low dropout voltage (e.g. 300mV at 600mA) and maintain very low quiescent current (70uA). The uP0111 does not require a bypass capacitor, hence achieving the smallest PCB area. The uP0111 is designed and optimized to work with lowvalue, low-cost ceramic capacitors. Only a 1uF ceramic output capacitor is required for stable operation for any load conditions. Other features include foldback overcurrent protection, quick soft start, and overtemperature protection. The uP0111 is available in fixed output voltages from 0.8V to 3.3V with 0.1V increments.

As shown in the *Functional Block Diagram*, the uP0111 consists of a bandgap for reference voltage, error amplifier, P-channel MOSFET pass transistor and internal feedback



# Functional Description

connected to the inverting input of error amplifier. The error amplifier compares this reference voltage with the feedback voltage and amplifies the difference. If the feedback voltage is lower than the reference voltage, the pass-transistor gate is pulled low. This allows more current to pass to the output and increases the output voltage. If the feedback voltage is too high, the pass transistor gate is pulled high, allowing less current to pass to the output. The output voltage is fed back through an internal or external resistor voltage-divider connected to the VOUT pin. Additional blocks include a current limiter, thermal sensor, and shutdown logic.

### **Supply Input Power On Reset**

The input voltage supplies current to the output voltage and supplies current for control circuit. The input voltage is monitored for power on reset (POR) to ensure the regulator is not enabled until the input voltage is high enough for normal operation. The POR threshold level is typical 2.1V at  $V_{\rm IN}$  rising.

### Enable/Shutdown

The uP0111 features an active-high enable pin that allows the regulator to be disabled. Forcing the enable pin lower than 0.35V shuts down the regulator and reduces its quiescent current less than 1uA. The voltage reference, error amplifier, gate-driver circuit and pass transistor are disabled in the shutdown state. When the regulator is in shutdown mode, an internal  $600\Omega$  resistor is connected between VOUT and GND. This is intended to discharge  $C_{\text{OUT}}$  when the LDO regulator is disabled. The internal  $600\Omega$  has no adverse effect on device turn-on time.

Forcing the enable pin higher than 1.2V enables the output voltage (once the input voltage is higher than its POR threshold level). If the enable function is not needed in a specific application, it may be tied to VIN to keep the regulator in an always on state. The enable pin uses CMOS technology and cannot be left floating, as this may cause an indeterminate state on the output.

### **Current Limit and Short-Circuit Protection**

The uP0111 includes a current limiter that monitors and controls the gate voltage of pass transistor to limit the output current to 1500mA typically. A short circuit protector monitors the output voltage and asserts output short circuit if  $V_{\text{OUT}}$  is lower than 40% of  $V_{\text{NOM}}$ . The current limiting level is reduced to 800mA. The output voltage is rebuilt after short circuit is removed.

### **Over Temperature Protection**

The overtemperature protection limits total power dissipation in the uP0111. When the junction temperature exceeds  $T_J = 170~^{\rm O}$ C, the thermal sensor signal the shutdowns logic, turning off the pass transistor and allows the device to cool down. The thermal sensor turns on the pass transistor again after the device junction temperature drops by  $40^{\rm O}$ C, resulting in a pulsed output during continuous during continuous thermal-overload conditions. The over temperature protection is designed to protect the device in the event of a fault condition. For continual operation, do not exceed the recommended temperature of  $T_J = 125~^{\rm O}$ C for maximum reliability.



	Absolute Maximum Rating
Supply Input Voltage V <sub>IN</sub> (Note 1)	0.3V to +6.5V
Other Pins	
Storage Temperature Range	
Junction Temperature	
Lead Temperature (Soldering, 10 sec)	
ESD Rating (Note 2)	
HBM (Human Body Mode)	2kV
MM (Machine Mode)	
	Thermal Information
	mermal information
Package Thermal Resistance (Note 3)	0500044
SOT23-3L θ <sub>JA</sub>	
SOT23-5L θ <sub>JA</sub>	
SOT89-3L θ <sub>JA</sub>	
SOT223-3L $\theta_{JA}$	
DFN3x3-8L θ <sub>JA</sub>	
DFN6x5-8L θ <sub>JA</sub>	
PSOP-8L 0 <sub>JA</sub>	
SOT23-3L θ <sub>JC</sub>	
SOT23-5L θ <sub>JC</sub>	
SOT89-3L θ <sub>JC</sub>	
SOT223-3L 0 <sub>JC</sub>	
DFN3x3-8L θ <sub>JC</sub>	
DFN6x5-8L θ <sub>JC</sub>	
PSOP-8L 0 <sub>JC</sub>	5°C/vv
Power Dissipation, $P_D @ T_A = 25^{\circ}C$	0.444
SOT23-3L	
SOT23-5L	
SOT89-3L	
SOT223-3L	
DFN3x3-8L	
DFN6x5-8L	
PSOP-8L	
	Recommended Operation Conditions
Operating Junction Temperature Range (Note 4)	
Operating Ambient Temperature Range	
Supply Input Voltage, V <sub>IN</sub>	+2.5V to +5.5V



# Electrical Characteristics

	T		1		1	
Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit
Supply Input Voltage						
Supply Input Voltage	V <sub>IN</sub>		2.5		5.5	V
POR Threshold	V <sub>PORTH</sub>			2.1		V
POR Hysteresis	V <sub>PORHYS</sub>			0.4		V
Quiescent Current	I <sub>Q</sub>	V <sub>EN</sub> = 5V, I <sub>OUT</sub> = 0mA	40	70	115	uA
Shutdown Current	I <sub>SHDN</sub>	V <sub>EN</sub> = 0V	-1	0.1	1	uA
Output Voltage			-			
Output Voltage Accuracy	V <sub>out</sub>	$V_{IN} = V_{NOM} + 1.0V; I_{OUT} = 1mA,$ fixed output voltage version	-1.5		1.5	%V <sub>NOM</sub>
Reference Voltage Accuracy	V <sub>FB</sub>	$V_{IN} = 3.3V$ , $I_{OUT} = 1$ mA, $VOUT = FB$ , adjustable output voltage version	0.788	0.80	0.812	V
Output Line Regulation	$\Delta V_{REF(LINE)}$	$I_{\rm OUT} = 1  {\rm mA}$ = 2.5V < V <sub>IN</sub> < 5.5V, and V <sub>IN</sub> > V <sub>OUT</sub> + 1.0V,		0.01	0.2	%/V
Output Load Regulation	$\Delta V_{REF(LOAD)}$	$1 \text{mA} < I_{\text{OUT}} < 500 \text{mA}, V_{\text{IN}} = V_{\text{NOM}} + 1.0 \text{V}$		0.5	1.0	%/A
Dropout Voltage	V <sub>DROP</sub>	I <sub>OUT</sub> = 300mA, 2.5V < V <sub>IN</sub> < 2.7V		180	240	mV
		I <sub>OUT</sub> = 600mA, 2.7V < V <sub>IN</sub> < 5.5V		300	400	
	PSRR	Frequency = 10Hz, I <sub>OUT</sub> = 10mA		68		dB
		Freequency = 1kHz, I <sub>OUT</sub> = 10mA		65		
Power Supply Rejection		Frequency = 100kHz, I <sub>OUT</sub> = 10mA		50		
Ratio		Frequency = 10Hz, I <sub>OUT</sub> = 300mA		48		
		Freequency = 1kHz, I <sub>OUT</sub> = 300mA		62		
		Frequency = 100kHz, <sub>IOUT</sub> = 300mA		65		
Enable			'			
Enable High Level	V <sub>EN</sub>		1.2			V
Disable Low Level	V <sub>SD</sub>				0.35	V
EN Input Current	I <sub>EN</sub>	$V_{IN} = 5.5V, V_{EN} = 5.5V \text{ or } 0V$	-1		1	uA
Enable Delay Time	T <sub>DELAY</sub>	form $V_{EN} > 1.2V$ to $V_{OUT} > 10\%V_{NOM}$ , by design		10		us
Output Ramp Up Time	T <sub>ss</sub>	from $V_{OUT} = 10\%$ to 90% of $V_{NOM}$ , by design		40		us



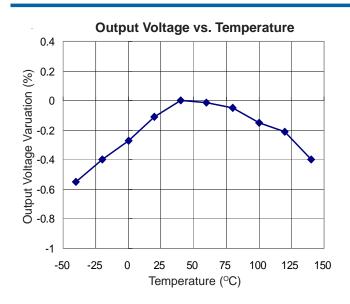
# Electrical Characteristics

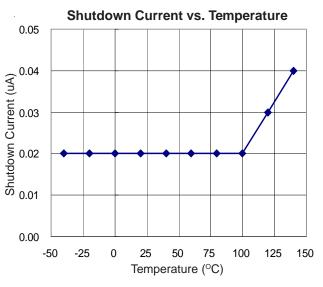
Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit
Protection						
Current Limit Threshold	I <sub>LIM</sub>		0.9	1.2	1.6	А
Short Circuit Current			0.6		1	Α
Thermal Shutdown Temperature	T <sub>SD</sub>	$I_{OUT} = 0 \text{mA}, V_{IN} = V_{EN} = 5.5 V_{IN}$		170		°C
Thermal Shutdown Hysteresis	T <sub>SDHYS</sub>	$I_{OUT} = 0 \text{mA}, \ V_{IN} = V_{EN} = 5.5 \text{V}$		40		°C

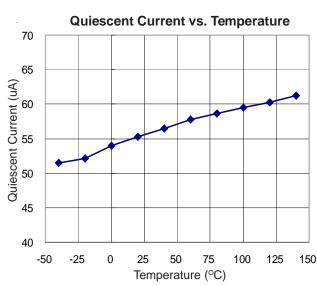
- **Note 1.** Stresses listed as the above "Absolute Maximum Ratings" may cause permanent damage to the device. These are for stress ratings. Functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may remain possibility to affect device reliability.
- Note 2. Devices are ESD sensitive. Handling precaution recommended.
- **Note 3.**  $\theta_{JA}$  is measured in the natural convection at  $T_A = 25^{\circ}\text{C}$  on a low effective thermal conductivity test board of JEDEC 51-3 thermal measurement standard.
- Note 4. The device is not guaranteed to function outside its operating conditions.

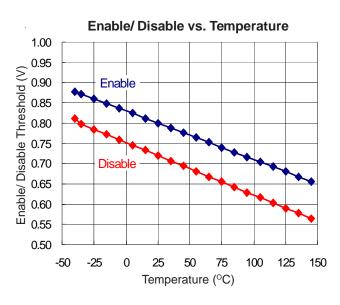


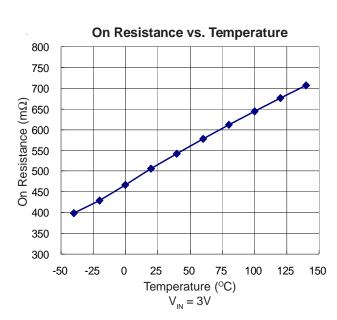
# **Typical Operation Characteristics**

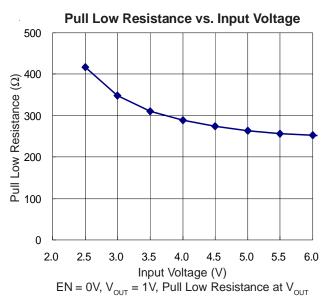






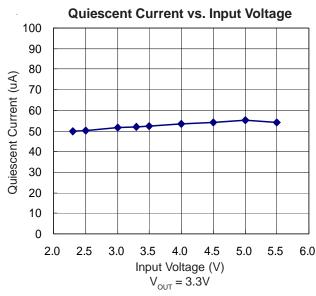


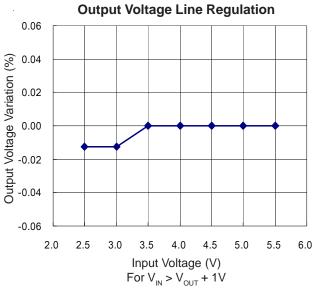


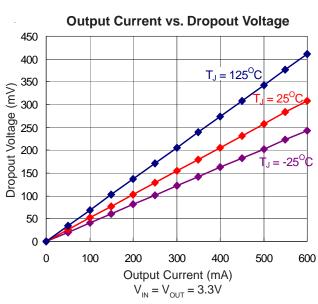


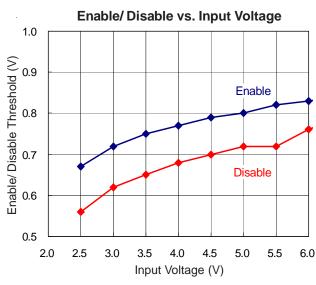


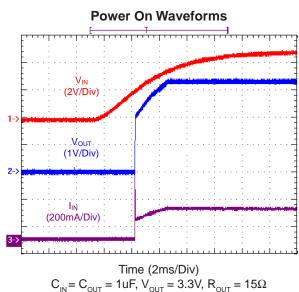
# **Typical Operation Characteristics**

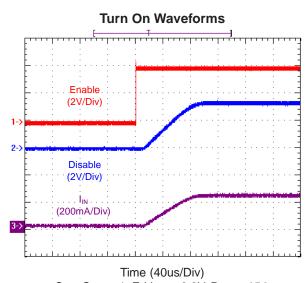








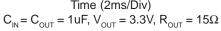






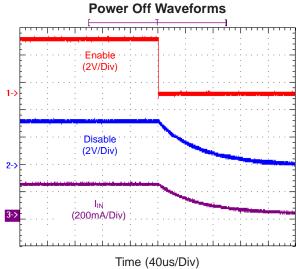
# **Typical Operation Characteristics**

# Power Off Waveforms V<sub>IN</sub> (2V/Div) 1-> (200mA/Div) Time (2ms/Div)



# Load Transient Response Vout (100mV/Div) 1-> (500mV/Div)

Time (20us/Div)  $C_{_{\rm IN}} = C_{_{\rm OUT}} = 1 u {\rm F, \ V}_{_{\rm OUT}} = 3.3 {\rm V, \ I}_{_{\rm OUT}} = 10 \ {\rm to \ 660 mA}$ 





# Application Information

The uP0111 is specially designed to provide low-noise, high PSRR output voltage without a bypassing capacitor on its reference voltage. However, input and output capacitor should be well considered for optimal performance.

### **Input Capacitors**

The uP0111 requires well-decoupled supply input for optimal performance. A minimum 1uF capacitor is required frominput-to-ground to provide stability. Input capacitors greater than 1uF offer superior input line transient response and will assist in maximizing the highest possible power supply ripple rejection ratio (PSRR). Ceramic, tantalum, or aluminum electrolytic capacitors may be selected for CIN. There is no specific capacitor ESR requirement for CIN. However, low-ESR ceramic capacitors provide optimal performance at a minimum of space and are highly recommended due to their inherent capability over tantalum capacitors to withstand input current surges from low impedance sources such as batteries in portable devices. Additional high frequency capacitors, such as small-valued NPO dielectric type capacitors, help filter out high-frequency noise and are good design practice in any RF-based circuit. Place the capacitors physically as close as possible to the device with wide and direct PCB traces.

### **Output Capacitors and Stability**

For proper load voltage regulation and operational stability, a capacitor is required between VOUT and GND pins. The uP0111 is designed and optimized to work with low-value, low-cost ceramic capacitors in space saving and performance consideration. Typical output capacitor values for maximum output current conditions range from 1uF to 10uF. Larger capacitors are recommended for applications expecting low output noise and optimum power supply ripple rejection characteristics. Place the capacitors physically as close as possible to the device with wide and direct PCB traces.

X7R/X5R dielectric-type ceramic capacitors are recommended because of their temperature performance. X7R type capacitors loss capacitance by 15% over their operating temperature rand and are the most stable type of ceramic capacitors. Z5U or Y5V dielectric capacitors loss their capacitance by 50% and 60% respectively over their operating temperature ranges. If Y5V or Z5U capacitors are used as output capacitors, the capacitance must be much higher than that of X7R capacitors to ensure the same minimum capacitance over the operating temperature range.

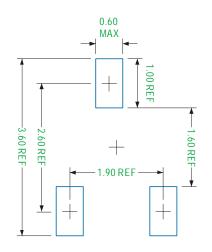
ESR of output capacitors should be well considered to ensure stable operation of the device. High ESR capacitors may cause high frequency oscillation. Figure 1 shows the acceptable ESR range of output capacitor for stability.

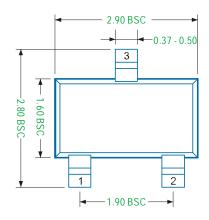
### No Load Stability

The uP0111 is designed to maintain output voltage regulation and stability under operational no load conditions. This is important characteristic for CMOS RAM keep-alive applications where the output current may drop to zero.

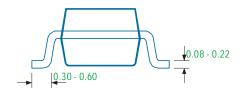


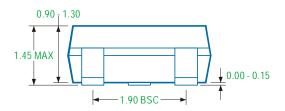
### SOT23-3L



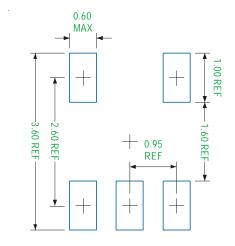


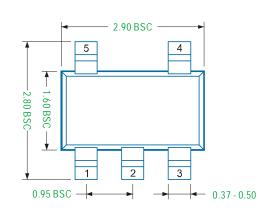
Recommended Solder Pad Layout



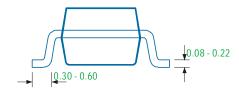


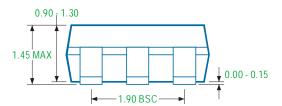
### SOT23-5L





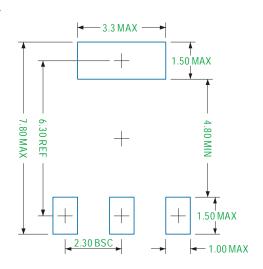
# Recommended Solder Pad Layout

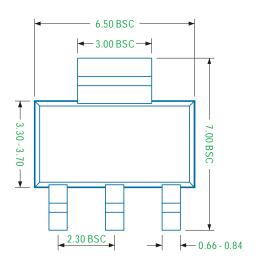






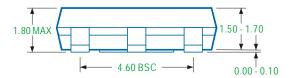
### SOT223 - 3L



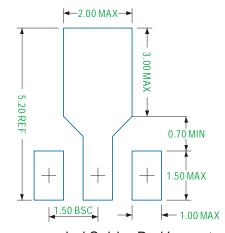


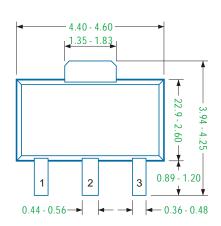
# Recommended Solder Pad Layout



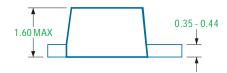


SOT89 - 3L





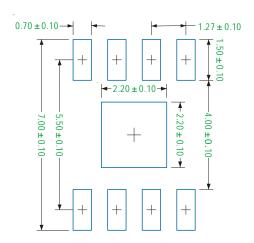
Recommended Solder Pad Layout

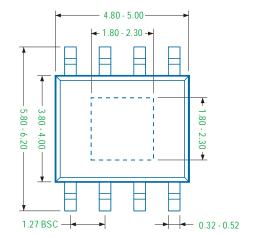






### PSOP - 8L





### Recommended Solder Pad Layout



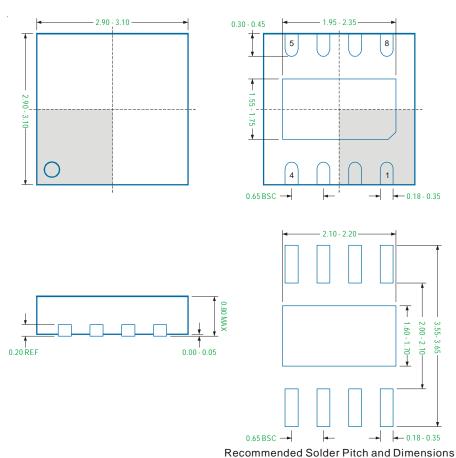


### Note

- 1. Package Outline Unit Description:
  - BSC: Basic. Represents theoretical exact dimension or dimension target
  - MIN: Minimum dimension specified.
  - MAX: Maximum dimension specified.
  - REF: Reference. Represents dimension for reference use only. This value is not a device specification.
  - TYP. Typical. Provided as a general value. This value is not a device specification.
- 2. Dimensions in Millimeters.
- 3. Drawing not to scale.
- 4. These dimensions no not include mold flash or protrusions. Mold flash or protrusions shell not exceed 0.15mm.



### DFN3x3 - 8L

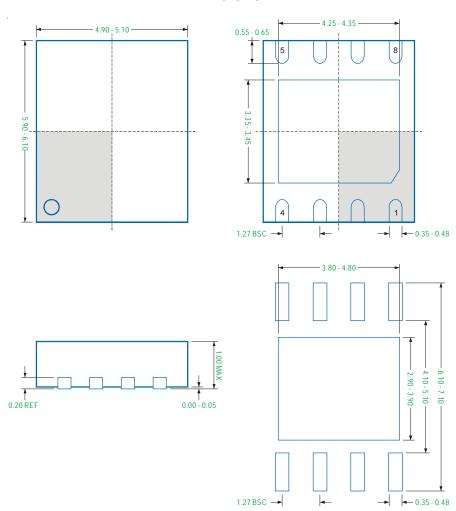


# Note

- 1. Package Outline Unit Description:
  - BSC: Basic. Represents theoretical exact dimension or dimension target
  - MIN: Minimum dimension specified.
  - MAX: Maximum dimension specified.
  - REF: Reference. Represents dimension for reference use only. This value is not a device specification.
  - TYP. Typical. Provided as a general value. This value is not a device specification.
- 2. Dimensions in Millimeters.
- 3. Drawing not to scale.
- 4. These dimensions no not include mold flash or protrusions. Mold flash or protrusions shell not exceed 0.15mm.



### DFN6x5 - 8L



Recommended Solder Pitch and Dimensions

### Note

- 1. Package Outline Unit Description:
  - BSC: Basic. Represents theoretical exact dimension or dimension target
  - MIN: Minimum dimension specified.
  - MAX: Maximum dimension specified.
  - REF: Reference. Represents dimension for reference use only. This value is not a device specification.
  - TYP. Typical. Provided as a general value. This value is not a device specification.
- 2. Dimensions in Millimeters.
- 3. Drawing not to scale.
- 4. These dimensions no not include mold flash or protrusions. Mold flash or protrusions shell not exceed 0.15mm.